

Kinetis FIT Summary

SUMMARY

The FIT data represented below is comprised of recent qualification HTOL device-level stress data for the Kinetis Family C90TFS (0, 1 and 2) N03G, 1N41K, 0/1N83J, 0N50M, 0N51M and 0N74K mask sets manufactured in the **Global Foundries Fab7** facility. Materials represented in these calculations are from the same technology and processes. These values are measures of observed accelerated life stress data and do not constitute guarantees of future performance levels. See below for actual results and FIT/MTTF assessments.

High Temperature Operational Life – Global Foundries

| STRESS | READ | Qty of | Qty of | % |
|--------------------------|-------|---------|---------|---------|
| | POINT | DEVICES | REJÉCTS | REJECTS |
| Q221591 1.558V core/125C | 1008 | 80 | 0 | 0 |
| Q221591 1.558V core/125C | 1008 | 80 | 0 | 0 |
| Q221591 1.558V core/125C | 1008 | 80 | 0 | 0 |
| Q222166 1.558V core/125C | 168 | 80 | 0 | 0 |
| Q225516 1.558V core/125C | 168 | 79 | 0 | 0 |
| Q224185 1.558V core/125C | 1008 | 80 | 0 | 0 |
| Q224185 1.558V core/125C | 168 | 77 | 0 | 0 |
| Q224185 1.558V core/125C | 168 | 80 | 0 | 0 |
| Q225446 1.6V Core/125C | 264 | 239 | 0 | 0 |
| Q226519 1.63V Core/125C | 264 | 80 | 0 | 0 |
| Q225737 1.6V Core/125C | 264 | 80 | 0 | 0 |
| Q227084 1.6V Core/125C | 264 | 79 | 0 | 0 |
| Q226520 1.63V Core/125C | 264 | 80 | 0 | 0 |

Note: Stress data collected in the above table is from initial qualification studies and onwards.

FIT Rates are calculated for each die size using the above data.

(0, 1 and 2) N03G and 1N41K: Current FIT data stands at 2.1 FIT at 60% Upper Confidence Limit at 55°C Tj constant duty cycle. Respective MTTF calculations are 53654.87.

(0/1N83J): Current FIT data stands at 2.5 FIT at 60% Upper Confidence Limit at 55°C Tj constant duty cycle. Respective MTTF calculations are 45984.14.

(0N50M): Current FIT data stands at 1.3 FIT at 60% Upper Confidence Limit at 55°C Tj constant duty cycle. Respective MTTF calculations are 85563.82.

(0N51M): Current FIT data stands at 1.3 FIT at 60% Upper Confidence Limit at 55°C Tj constant duty cycle. Respective MTTF calculations are 85563.82.

(0N74K): Current FIT data stands at 0.9 FIT at 60% Upper Confidence Limit at 55°C Tj constant duty cycle. Respective MTTF calculations are 131130.89.

Please note; larger die size results in higher FIT rates and lower MTTF values; therefore each mask calculation is provided above. Lower junction temperatures and duty cycles will result in lower FIT rates and higher MTTF values.

DESCRIPTION OF STRESS TEST

High Temperature Operational Life test (HTOL)

150° or 125°C, 1.558, 1.6, 1.63 Volts

To determine the constant failure rate of the product at the specified operating temperature (usually 55-70°C), by Last update 4 March 2015

accelerating temperature and voltage-activated failure mechanisms to produce device failures.

A dynamic electrical bias is applied to stimulate the device during the life test. Microcontrollers are cycled through software routines, developed to stress the devices to simulate actual use, at elevated temperature and voltage. Reject quantities at the test temperature are modified by the Chi-squared distribution function at 90% confidence levels. The failure rates are then calculated and derated to the required temperature using the Arrhenius equation with a 0.54 eV activation energy assumed as an average for the failure mechanisms. Further details are given in 'Calculation of Failure Rates'.

CALCULATION OF FAILURE RATES

Life test is a technique for determining constant failure rate. To derate from the temperature at which the life test is carried out to the maximum operating temperature an acceleration factor is applied. This calculation uses the Arrhenius equation, with **0.54eV** assumed for the activation energy.

Temperature Acceleration Factor, Aft = exp (θ/k (1/To - 1/Tt))

| Where: | θ is activation energy (eV) | |
|--------|--|--|
| | k is Boltzmann's constant (8.617 x 10 $^{-5}$ eV/K) (K = -273.16°C) | |
| | $To = Ta (op) + (Pd x \theta ja)$ | |
| | $Tt = Ta (tst) + (Pd \times \theta ja)$ | |
| And: | a (op) is the ambient user operating temperature (K) a (tst) is the ambient temperature on stress test (K) d is power dissipated by the device (W) ja is thermal resistance of the package (°C/W) | |

Rejects obtained in the sample must be modified at a stated confidence level to obtain the rejects which would occur were the entire population tested. This is done using the Chi-square distribution function.

Failure Rate, Fa = Z / (2 x N x h x Aft)

where: Z is Chi-square $(\chi 2)$ reject quantity N is number of devices on test h is test duration (hours)

* Fa is multiplied by 10⁹ to give the result in FITS

* Fa is multiplied by 10⁵ for % per 1000 hours.

 $(1 \text{ FIT} = 1 \text{ failure in } 10^9 \text{ device hours}).$

 χ^2 value Z, is derived from statistical tables using (2 x Qty. fails + 2) for the Degrees of Freedom:

| Qty fails | 60% confidence | 90% confidence | |
|-----------|----------------|----------------|--|
| | level χ2 qty | level χ2 qty | |
| 0 | 1.833 | 4.605 | |
| 1 | 4.045 | 7.779 | |
| 2 | 6.211 | 10.645 | |
| 3 | 8.351 | 13.362 | |
| 4 | 10.473 | 15.987 | |
| 5 | 12.584 | 18.549 | |
| 6 | 14.685 | 21.064 | |
| 7 | 16.780 | 23.542 | |
| 8 | 18.868 | 25.989 | |
| 9 | 20.951 | 28.412 | |

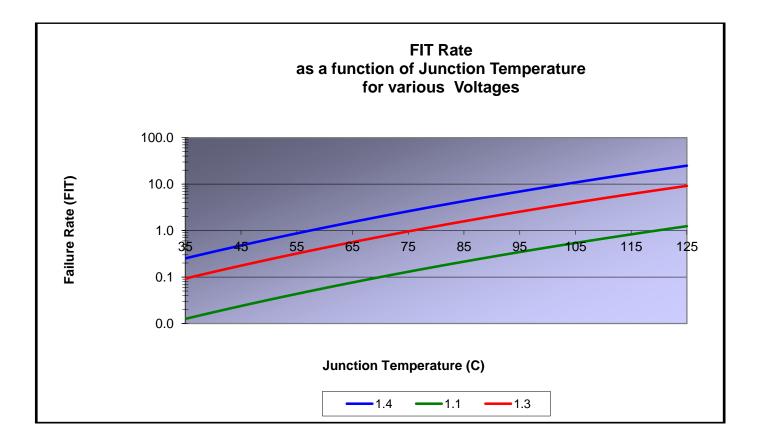
Voltage Acceleration is also taken into account when determining the life of devices. This is calculated by taking the oxide thickness into consideration and derating from the stress test voltage to the life operating voltage.

Voltage Acceleration Factor, $Afv = exp \beta [Vt - V_0]$

Where:

 $\begin{array}{l} \text{Vo} = \text{Gate voltage under typical operating conditions (in Volts)} * \\ \text{Vt} = \text{Gate voltage under accelerated test conditions (in Volts)} * \\ \\ \beta = \text{Voltage acceleration factor (in 1/Volts)} \end{array}$

* For devices with dual gate oxide, the thin gate oxide voltages are applicable. ** Specified by technology in the Reliability Model document 68MWS00084B.



Family 60% FIT Curve Based on HTOL Stress data provided above

